

# Vishay General Semiconductor

# **Glass Passivated Junction Fast Switching Rectifier**



technique is covered by Patent No. 3,996,602, brazed-lead assembly by Patent No. 3.930.306 DO-204AL (DO-41)

| PRIMARY CHARACTERISTICS |                        |  |  |  |  |
|-------------------------|------------------------|--|--|--|--|
| I <sub>F(AV)</sub>      | 1.0 A                  |  |  |  |  |
| $V_{RRM}$               | 400 V to 1000 V        |  |  |  |  |
| I <sub>FSM</sub>        | 20 A                   |  |  |  |  |
| t <sub>rr</sub>         | 150 ns, 250 ns, 500 ns |  |  |  |  |
| I <sub>R</sub>          | 5.0 μΑ                 |  |  |  |  |
| V <sub>F</sub>          | 1.3 V                  |  |  |  |  |
| T <sub>J</sub> max.     | 175 °C                 |  |  |  |  |

### **FEATURES**

Superectifier structure for high reliability condition



- · Cavity-free glass-passivated junction
- Fast switching for high efficiency
- Low leakage current, typical I<sub>R</sub> less than  $0.1 \mu A$

- · High forward surge capability
- Meets environmental standard MIL-S-19500
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

### TYPICAL APPLICATIONS

For general purpose of medium frequency rectification.

### **MECHANICAL DATA**

Case: DO-204AL, molded epoxy over glass body

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

| <b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)                                   |                                   |               |         |          |         |      |
|--|-----------------------------------|---------------|---------|----------|---------|------|
| PARAMETER  | SYMBOL                            | BA157GP       | BA158GP | BA159DGP | BA159GP | UNIT |
| Maximum repetitive peak reverse voltage  | V <sub>RRM</sub>                  | 400           | 600     | 800      | 1000    | V    |
| Maximum RMS voltage  | V <sub>RMS</sub>                  | 280           | 420     | 560      | 700     | V    |
| Maximum DC blocking voltage  |                                   | 400           | 600     | 800      | 1000    | V    |
| Maximum average forward rectified current 0.375" (9.5 mm) lead length at $T_{A}$ = 55 $^{\circ}\text{C}$ | I <sub>F(AV)</sub>                | 1.0           |         |          |         | А    |
| Peak forward surge current 10 ms single half sine-wave superimposed on rated load                        | I <sub>FSM</sub>                  | 20            |         |          | А       |      |
| Operating junction and storage temperature range   | T <sub>J</sub> , T <sub>STG</sub> | - 65 to + 175 |         |          |         | °C   |

| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted) |   |                                 |         |         |          |         |      |
|---|---|---------------------------------|---------|---------|----------|---------|------|
| PARAMETER   | TEST CONDITIONS   | SYMBOL                          | BA157GP | BA158GP | BA159DGP | BA159GP | UNIT |
| Maximum instantaneous forward voltage   | 1.0 A   | V <sub>F</sub>                  | 1.3     |         |          | ٧       |      |
| Maximum DC reverse current at rated DC blocking voltage                           | T <sub>A</sub> = 25 °C  | I <sub>R</sub>                  | 5.0     |         |          | μΑ      |      |
| Maximum reverse recovery time   | I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1.0 A,<br>I <sub>rr</sub> = 0.25 A | t <sub>rr</sub> 150 250 500 500 |         | 500     | ns       |         |      |
| Typical junction capacitance  | 4.0 V, 1 MHz  | CJ                              | 15      |         |          | pF      |      |

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| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |                 |         |         |          |         |      |
|---|-----------------|---------|---------|----------|---------|------|
| PARAMETER   | SYMBOL          | BA157GP | BA158GP | BA159DGP | BA159GP | UNIT |
| Typical thermal resistance (1)  | $R_{\theta JA}$ | 55      |         |          | °C/W    |      |

### Note:

(1) Thermal resistance from junction to ambient at 0.375" (9.5 mm) lead length, P.C.B. mounted

| ORDERING INFORMATION (Example) |                 |                        |               |                                  |  |  |  |
|--------------------------------|-----------------|------------------------|---------------|----------------------------------|--|--|--|
| PREFERRED P/N                  | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE                    |  |  |  |
| BA158GP-E3/54                  | 0.336           | 54                     | 5500          | 13" Diameter paper tape and reel |  |  |  |
| BA158GP-E3/73                  | 0.336           | 73                     | 3000          | Ammo pack packaging              |  |  |  |
| BA158GPHE3/54 (1)              | 0.336           | 54                     | 5500          | 13" Diameter paper tape and reel |  |  |  |
| BA158GPHE3/73 (1)              | 0.336           | 73                     | 3000          | Ammo pack packaging              |  |  |  |

### Note:

(1) Automotive grade AEC Q101 qualified

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

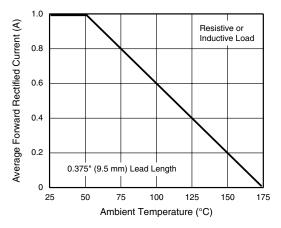


Figure 1. Forward Current Derating Curve

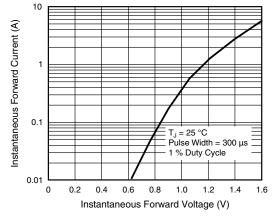


Figure 3. Typical Instantaneous Forward Characteristics

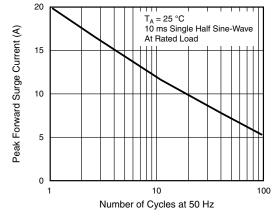


Figure 2. Maximum Non-repetitive Peak Forward Surge Current

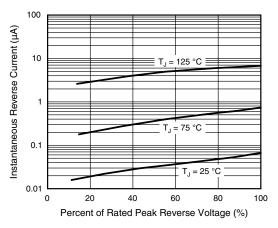


Figure 4. Typical Reverse Characteristics



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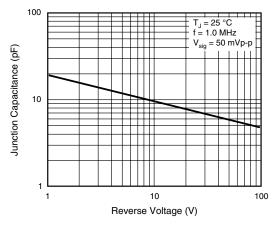


Figure 5. Typical Junction Capacitance

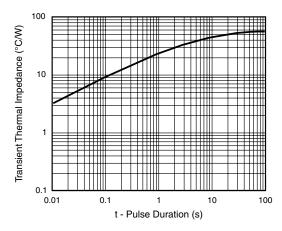


Figure 6. Typical Transient Thermal Impedance

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

# DO-204AL (DO-41) 1.0 (25.4) MIN. 0.107 (2.7) 0.080 (2.0) DIA. 0.205 (5.2) 0.160 (4.1) 1.0 (25.4) MIN. 1.0 (25.4) MIN.

Note: Lead diameter is  $\frac{0.026~(0.66)}{0.023~(0.58)}$  for suffix "E" part numbers



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